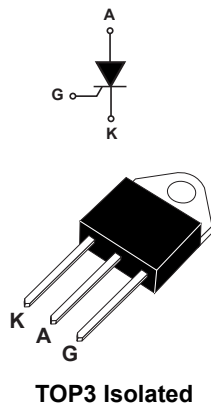


50 A 800 V SCR in TOP3 insulated



Features

- Max. repetitive blocking voltage = V_{DRM} , V_{RRM} = 800 V
- I_{GT} maximum = 80 mA
- ECOPACK^{®2} component (RoHS and HF compliance)
- Complies with UL 1557 standard (File ref : E81734)

Applications

- Solid state relays
- Welding equipment
- High power motor control
- Heating systems
- Controlled AC/DC bridge

Description

Available in a high power package TOP3-I, the **BTW69-800** is suitable in applications where power handling and power dissipation are critical, such as solid state relays, welding equipment, high power motor control and power converters.

This device offers a superior performance in surge current handling capabilities, allowing usage in industrial environment.

Thanks to its internal ceramic pad, it provide high voltage insulation (2500V_{RMS}), complying with UL standards (file ref: E81734).

Product status link

[BTW69-800](#)

Product summary

| | |
|-------------------|-------|
| $I_{T(RMS)}$ | 50 A |
| V_{DRM}/V_{RRM} | 800 V |
| I_{GT} | 80 mA |

1 Characteristics

Table 1. Absolute maximum ratings

| Symbol | Parameters | | Value | Unit | |
|--------------|--|--|-----------------------|-------------|------------------|
| $I_{T(RMS)}$ | RMS on-state current (180° conduction angle) | | $T_C = 75\text{ °C}$ | 50 | A |
| $I_{T(AV)}$ | Average on-state current (180° conduction angle) | | $T_C = 75\text{ °C}$ | 32 | A |
| I_{TSM} | Non repetitive surge peak on-state current (full cycle, T_j initial = 25 °C, $V_R = 0$ V) | | $t_p = 8.3\text{ ms}$ | 610 | A |
| | | | $t_p = 10\text{ ms}$ | 580 | |
| I^2t | I^2t value for fusing | $t_p = 10\text{ ms}, T_j = 25\text{ °C}$ | | 1680 | A ² s |
| di/dt | Critical rate of rise of on-state current $I_G = 2 \times I_{GT}, t_r \leq 100\text{ ns}$ | $F = 60\text{ Hz}$ | $T_j = 125\text{ °C}$ | 50 | A/ μ s |
| I_{GM} | Peak gate current | $t_p = 20\text{ }\mu$ s | $T_j = 125\text{ °C}$ | 8 | A |
| $P_{G(AV)}$ | Average gate power dissipation | | $T_j = 125\text{ °C}$ | 1 | W |
| T_{stg} | Storage junction temperature range | | | -40 to +150 | °C |
| T_j | Operating junction temperature range | | | -40 to +125 | °C |
| V_{GRM} | Maximum peak reverse gate voltage | | | 5 | V |
| V_{ins} | Insulation RMS voltage, 1 minute | | | 2500 | V |

Table 2. Electrical characteristics ($T_j = 25\text{ °C}$, unless otherwise specified)

| Symbol | Test conditions | T_j | | Value | Unit |
|-------------------|--|--------|------|-------|------------|
| I_{GT} | $V_D = 12\text{ V}, R_L = 33\text{ }\Omega$ | | Min. | 8 | mA |
| | | | Max | 80 | |
| V_{GT} | | | Max | 1.3 | V |
| V_{GD} | $V_D = V_{DRM}, R_L = 3.3\text{ k}\Omega$ | 125 °C | Min. | 0.2 | V |
| I_H | $I_T = 500\text{ mA}$, gate open | | Max. | 150 | mA |
| I_L | $I_G = 1.2 \times I_{GT}$ | | Max. | 200 | mA |
| dV/dt | $V_D = 67\%$, V_{DRM} gate open | 125 °C | Min. | 1000 | V/ μ s |
| V_{TM} | $I_{TM} = 100\text{ A}$, $t_p = 380\text{ }\mu$ s | | Max. | 1.9 | V |
| V_{TO} | Threshold on-state voltage | 125 °C | Max. | 1.0 | V |
| R_D | On-state dynamic resistance | 125 °C | Max. | 8.5 | m Ω |
| I_{DRM}/I_{RRM} | $V_D = V_{DRM}, V_R = V_{RRM}$ | 25 °C | Max. | 10 | μ A |
| | | 125 °C | | 5 | mA |

Table 3. Thermal resistance

| Symbol | Parameters | Value | Unit |
|---------------|---------------------------|-------|------|
| $R_{th(j-c)}$ | Junction to case (D.C) | 0.9 | °C/W |
| $R_{th(j-a)}$ | Junction to ambient (D.C) | 50 | |

1.1 Characteristics (curves)

Figure 1. Maximum average power dissipation versus average on-state current

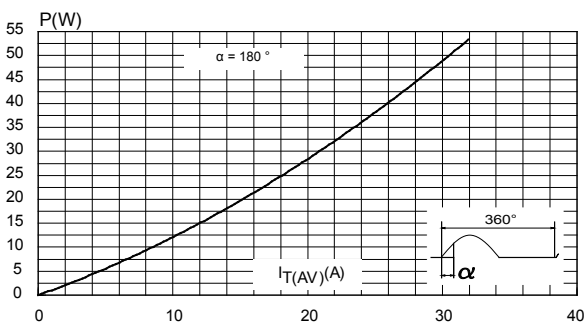


Figure 2. Average on-state current versus case temperature

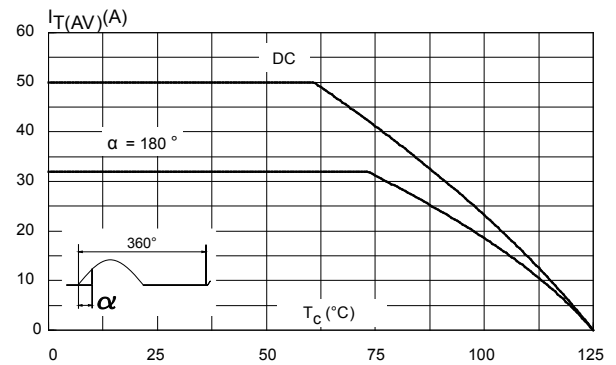


Figure 3. Relative variation of thermal impedance versus pulse duration

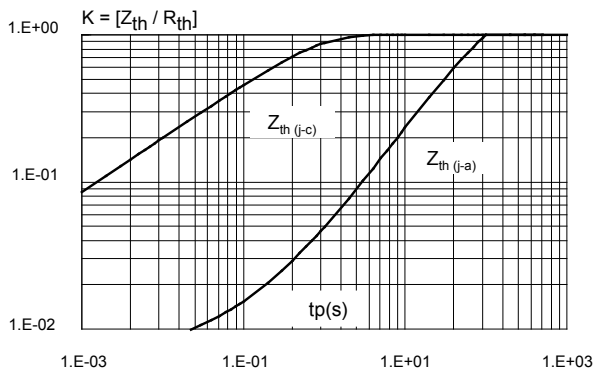


Figure 4. Relative variation of gate trigger current, holding current and latching current versus junction temperature

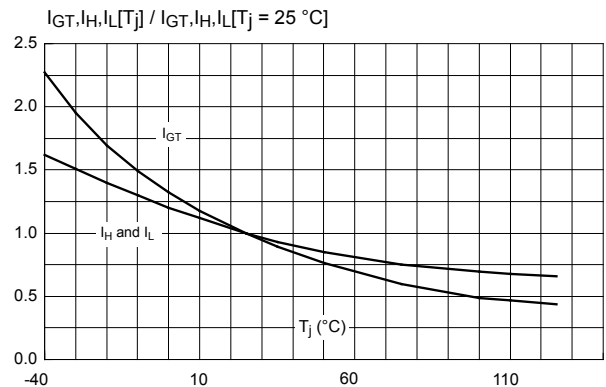


Figure 5. Surge peak on-state current versus number of cycles ($V_R = 0$ V)

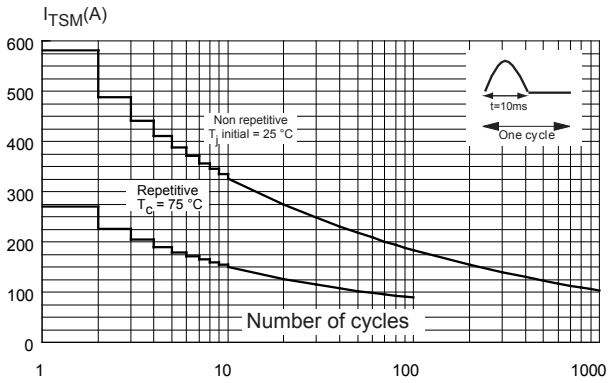


Figure 6. Non repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10$ ms, and corresponding value of I^2t ($V_R = 0$ V)

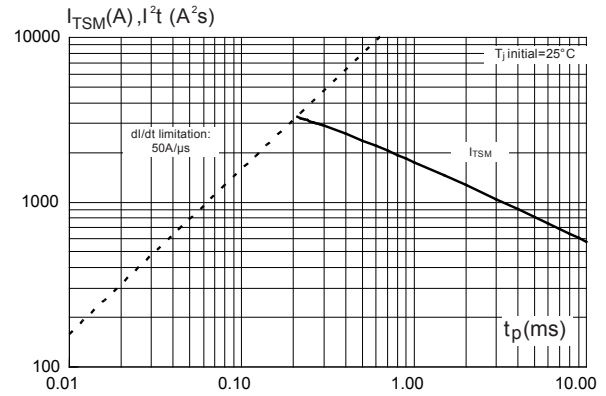
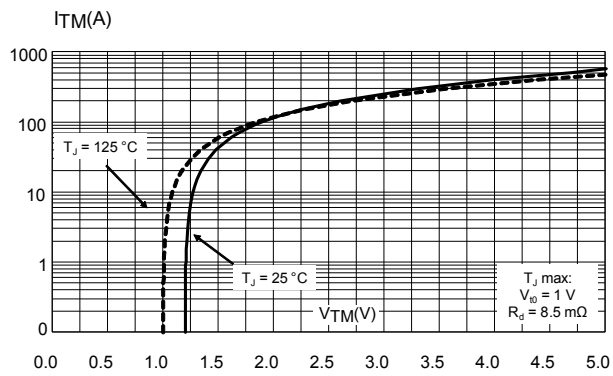


Figure 7. On-state characteristics (maximum values)



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 TOP3 Ins. package information

- **ECOPACK®** (Lead-free plating and Halogen free package compliance)
- Lead-free package leads finishing
- Halogen-free molding compound resin meets UL94 standard level V0
- Recommended torque: 1.05 N·m (max. torque: 1.2 N·m)

Figure 8. TOP3 Isolated package outline

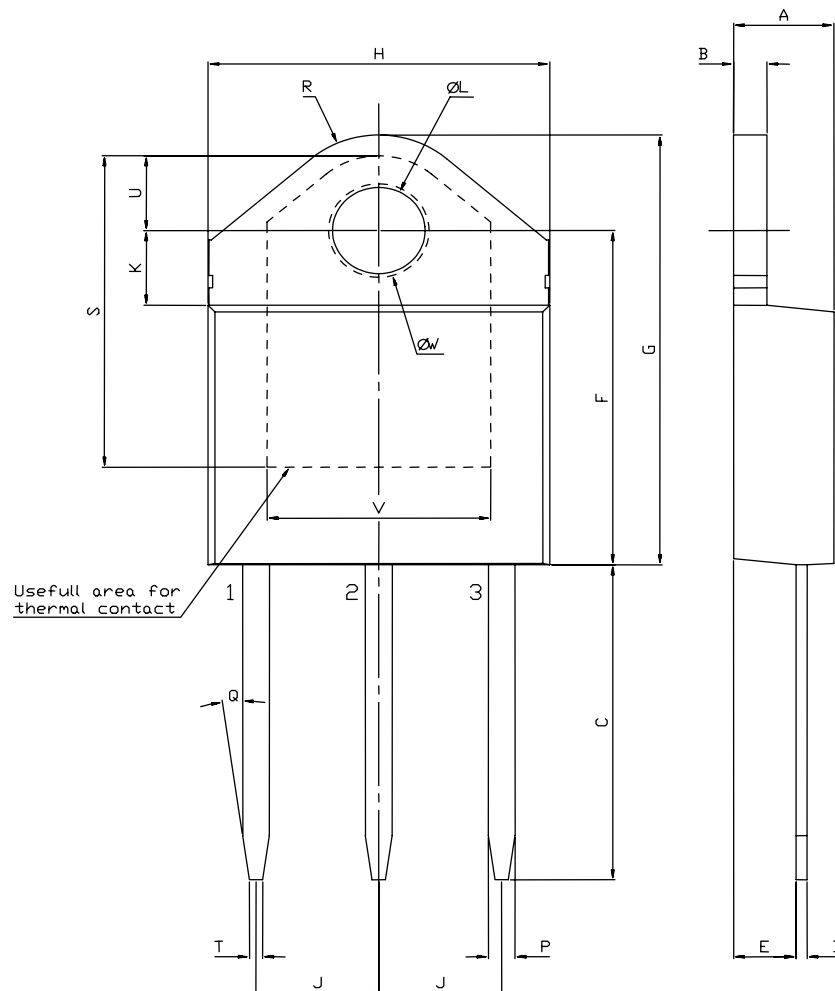


Table 4. TOP3 Isolated mechanical data

| Ref. | Dimensions | | | | | |
|------|------------|------|-------|-----------------------|--------|--------|
| | mm | | | Inches ⁽¹⁾ | | |
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 4.40 | | 4.60 | 0.1732 | | 0.1811 |
| B | 1.45 | | 1.55 | 0.0571 | | 0.0610 |
| C | 14.35 | | 15.60 | 0.5650 | | 0.6142 |
| D | 0.50 | | 0.70 | 0.0197 | | 0.0276 |
| E | 2.70 | | 2.90 | 0.1063 | | 0.1142 |
| F | 15.80 | | 16.50 | 0.6220 | | 0.6496 |
| G | 20.40 | | 21.10 | 0.8031 | | 0.8307 |
| H | 15.10 | | 15.50 | 0.5945 | | 0.6102 |
| J | 5.40 | | 5.65 | 0.2126 | | 0.2224 |
| K | 3.40 | | 3.65 | 0.1339 | | 0.1437 |
| L | 4.08 | | 4.17 | 0.1606 | | 0.1642 |
| M | 1.20 | | 1.40 | 0.0472 | | 0.0551 |
| R | | 4.60 | | | 0.1811 | |

1. Inches given for reference only

3 Ordering information

Figure 9. Ordering information scheme

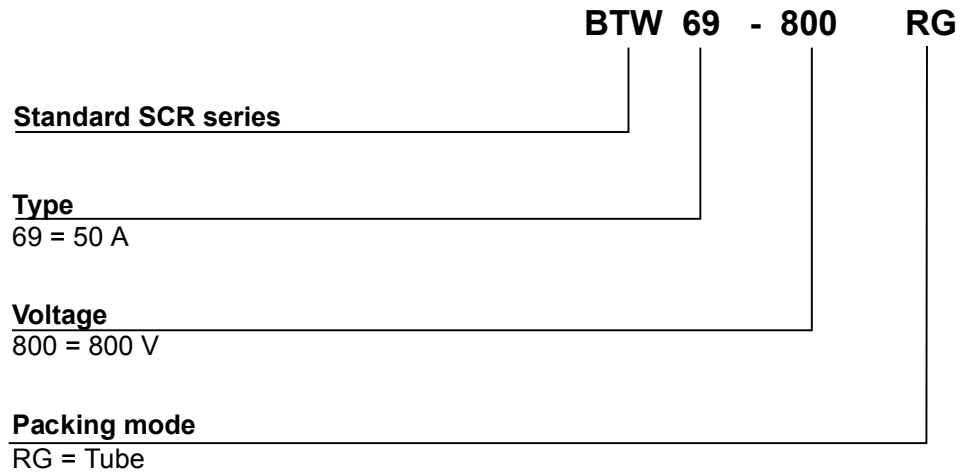


Table 5. Ordering information

| Order code | Marking | Package | Weight | Base qty. | Delivery mode |
|-------------|----------|-----------|--------|-----------|---------------|
| BTW69-800RG | BTW69800 | TOP3 Ins. | 4.5 g | 30 | Tube |

Revision history

Table 6. Document revision history

| Date | Revision | Changes |
|-------------|----------|------------------|
| 09-Sep-2019 | 1 | Initial release. |

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